



Insights into electrodeposition and catalytic activity of MoS₂ for hydrogen evolution reaction electrocatalysis



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ABSTRACT

MoS_{2-x} films were electrodeposited cathodically onto copper rod substrates from a solution, containing MoS₄²⁻ as the common Mo and S ion precursor. The catalyst loading was varied by adjusting electrodeposition conditions – applied potential and deposition time. A typical set of HER electrocatalyst experiments (polarization, Tafel slope analysis) carried out in 0.5 M H₂SO₄ was applied on the deposited MoS_{2-x} films. Analysis of surface morphology (SEM) and chemical composition (EDS) were also performed. Electrochemical impedance spectroscopy in the same acidic media was used to evaluate the catalyst–solution interface and the interfacial kinetics (by calculating double layer capacitance and charge transfer resistance), as well as characterize the hydrogen adsorption process (adsorption capacitance and resistance). A linear correlation between electrodeposition time and double layer capacitance was observed. However, the charge transfer resistance was found to decrease until it plateaued at longer deposition times. The MoS_{2-x} film, deposited for 7200 s at –1.0 V (vs. Ag/AgCl), reached 10 mA cm⁻² HER current at –0.18 V (vs. RHE), and represented the best result of this study. Electrochemical impedance spectroscopy (EIS) was further applied to evaluate the subtle changes in the MoS_{2-x} films' semiconductor properties after HER stability tests (at –40 mA cm⁻²), and to estimate the number of active sites on the material. EIS, in comparison to cyclic voltammetry or roughness factor calculations, is a completely non-destructive method that can be applied to accurately assess the system under investigation.

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1. Introduction

Contemporary research into renewable energy always faces a common issue, namely: what can be used as an energy carrier from production to consumption. Hydrogen is considered as a potential alternative to hydrocarbons [1], but for a true breakthrough in hydrogen fuel cells more effective methods of H₂ generation and storage must be discovered. Photo- or electrochemical water splitting can be a source of clean H₂ fuel, but the process is hindered by unfavourable kinetics, and for efficient, large-scale application a catalyst is required [2].

Molybdenum sulphide compounds have been an object of research since at least 1977 [3–5], and have been thoroughly investigated for their semiconductor, photo-, and electrochemical properties. Extensive review papers have also been published

recently [6–8].

Their electrocatalytic properties towards the hydrogen evolution reaction were elucidated in an attempt to mimic the effects of biological enzymes [9]. In their seminal work, B. Hinnemann et al. proposed that an ideal catalyst would have a free energy of adsorbed H of $\Delta G^H_0 \approx 0$. In other words, hydrogen evolution catalysis would obey the Sabatier principle: the chemical interactions between the catalyst and the substrate should be “just right”; that is, neither too strong nor too weak. A sufficient understanding of the various active centres is important when working with any heterogeneous catalysis, and this was also the case with molybdenum sulphide. Early research showed, that bulk MoS₂ (i.e. the basal plane) is a poor HER catalyst [10]. It became known later that edge sites are one of the active sites for H₂ evolution [11], and that HER activity would scale with their amount in the catalyst. However, when comparing edge-site-rich MoS₂ flakes with a monolayer film, it was found that the film exhibited much better HER activity, which led to proof of the importance of different active sites – sulphur vacancies ($\Delta G^H_0 \approx -0.095$ eV) [12]. Currently, the active sites of MoS₂ are thought to be Mo edge sites

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($\Delta G^H_0 \approx 0.115$ eV), S vacancies, and grain boundaries ($\Delta G^H_0 \approx 0.181$ – 0.566 eV). The basal plane is effectively inert at $\Delta G^H_0 \approx 1.218$ eV. It may also be important to mention that not all commercially available MoS₂ is equal, as it was found that the HER properties of MoS₂, obtained from different suppliers, varies greatly due to different methods of preparation [13].

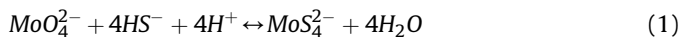
Coatings of unique compositions, crystallographic structures, surface morphologies, and catalytic properties, have been synthesized using chemical vapour deposition [14,15], hydro- or solvothermal deposition [16–18], the increasingly popular chemical exfoliation method, electrodeposition [19–23], and more. Incorporation of naturally-occurring molybdenite has also been shown to greatly enhance the HER catalytic properties of electrodeposited Ni films in alkaline media [24]. Electrodeposited molybdenum disulphide films consist of nonstoichiometric, amorphous MoS_{2-x} that is particularly active towards HER [25,26]. However, they are less stable in comparison to crystalline MoS₂ materials [27]. Some of the earlier studies on the electrodeposition of MoS₂ have reported the method involving a cathodic reduction of aqueous ammonium tetrathiomolybdate ((NH₄)₂MoS₄) [28]. It was found, that electrodeposition begins at -0.9 V (vs. SCE) and reaches a maximum of 30% current efficiency at -1.2 V to -1.4 V, then decreases at more negative potentials due to hydrogen evolution. A linear correlation was found between the electrodeposited film thickness and the charge passed through the cell. On the other hand, oxidative deposition of tetrathiomolybdate solutions at anodic potentials yields the formation of MoS₃ [4,5], which also has attractive electrochemical properties. A mixture of MoS₂ and MoS₃ has been electrodeposited by applying a potential cycling method between cathodic and anodic deposition modes, resulting in a MoS_{2+x} film possessing mixed electrocatalytic capabilities [29].

The stability of electrodeposited MoS₂ seems to be an often-omitted issue. Although most research reports satisfactory or even excellent electrochemical stability, some authors have reported that thicker films (>1 μm) peeled off from the substrate [28,30], and that cracks could appear during drying. Furthermore, for a MoS₂ monolayer (grown by CVD and aged for 1 year) XPS analysis showed that the Mo/S ratio decreased from 1/2 to 1/1.05 due to oxidation of sulphide sites [31]. Calculations based on Density Functional Theory (DFT) revealed, that on a S-deficient MoS₂ surface the kinetic O₂ dissociative adsorption barrier is relatively low, meaning that the oxidation (passivation) of active sites is thermodynamically favourable [32]. Edge sites and grain boundaries were also found to be susceptible to oxidation, and it was theorized, that the misfit between the MoS₂ and MoO₃ lattices may be the cause of the mechanical stress that causes MoS₂ cracking [33].

Ultimately, during recent years strides have been made in the understanding of amorphous MoS_{2-x} compounds. Raman spectroscopy experiments have unravelled different S–S bonds in electrodeposited MoS₂, representing bridging/shared and terminal disulphide bonds. It was revealed that the structure of MoS₂ is a polymer, composed of [Mo₃S₁₃]²⁻ clusters connected via disulphide ligands [34]. This structure is currently thought to explain the empirically observed peculiarities of amorphous MoS₂: the unprecedented HER electrocatalytic activity (the active unsaturated Mo^{IV} sites/sulphur vacancies have a favourable ΔG^H_0), the reductive activation of some MoS₂ compounds (removal of terminal disulphide ligands, resulting in more unsaturated Mo^{IV} sites), and the cathodic corrosion (shortening of the polymer chains). Taking into account what was mentioned above, the present research is devoted to extending the knowledge into the electrodeposition of MoS₂, and its catalytic activity for hydrogen evolution reaction.

2. Experimental

Electrolyte preparation. Molybdenum disulphide films were electrodeposited from a solution containing a common precursor of Mo⁶⁺ and S²⁻ ions – tetrathiomolybdate (TTM/MoS₄²⁻). In order to prepare the electrolyte, ammonium heptamolybdate tetrahydrate ((NH₄)₆Mo₇O₂₄·4H₂O) and 60% sodium sulphide hydrate (Na₂S·xH₂O) were mixed in a ratio of Mo/S = 1/4. The sulfidation of molybdate ions (MoO₄²⁻) to tetrathiomolybdate is a four-step reaction, where each step is reversible, and the total reaction can be represented as follows:



The pH of the mixture was ~12, and it was acidified up to pH of 7 with sulfuric acid to push the reaction equilibrium towards the product side and to favour the formation of MoS₄²⁻ over the intermediates. The reference indicator of MoS₄²⁻ formation was the solution colour changing to a deep red. 25 ml of 2-propanol was added to the electrolyte in order to decrease surface tension and increase wettability of the working electrode. The final electrolyte composition contained: C_{MoS₄²⁻} = 0.025 M + 10% of 2-propanol. The pH was kept weakly alkaline (pH ~ 8) to prevent precipitation of insoluble MoS₃.

MoS₂ electrodeposition. All electrochemical measurements were carried out using a standard three-electrode cell set-up (potentiostat/galvanostat Metrohm μAutolab Type III). Unless specified otherwise, all potentials were referenced to Ag/AgCl. The copper rod substrates were prepared to have a 1 cm² working surface area. They were first polished with a commercial detergent, then immersed in 2 M H₂SO₄ to dissolve surface oxides, rinsed with distilled water, and finally degreased with 2-propanol. Initially, linear sweep voltammetry measurements were carried out to determine the electrodeposition potential range in the investigated electrolyte. MoS_{2-x} films were deposited under potentiostatic mode, at various cathodic potentials (-0.8 V to -1.2 V); or at constant potential (-1.0 V), but for different deposition times (200 s–7200 s). The surface morphology and chemical composition of the electrodeposited MoS_{2-x} films were evaluated using a Hitachi TM 3000 Scanning Electron Microscope with an integrated EDX module.

Electrocatalytic activity measurements. To measure the electrocatalytic activity towards hydrogen evolution, the as-deposited MoS₂ films were rinsed with distilled water and immediately transferred to a 0.5 M H₂SO₄ solution. A multi-faceted characterization of the obtained MoS₂ films towards HER consisted of the following measurements: a) open circuit potential (OCP) determination; b) electrochemical impedance spectroscopy (EIS) at -0.32 V vs. Ag/AgCl (-0.1 V vs. RHE); c) ten linear sweep voltammetry (LSV) curves at 10 mV s⁻¹ from OCP to -40 mA cm⁻² cut-off condition; d) stability measurement for 20 min at -40 mA cm⁻².

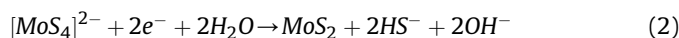
Registering an electrochemical impedance spectrum before electrocatalytic measurements served two purposes: it allowed analysis of the catalyst in a non-destructive way, and supplied an accurate value of electrolyte resistance (for *iR* correction). Accordingly, all polarization curves were corrected for the *iR* drop.

In addition, EIS was used to estimate the H⁺ adsorption and double layer capacitances (C_d and C_{dl}) of the electrodeposited MoS_{2-x} films. The cathodic overpotential for EIS recording was chosen to be not far from Nernst potential (-0.1 V). HER polarization experiments showed that at this overpotential range the reaction of hydrogen evolution occurs slowly. EIS spectra were measured in the range 10 kHz – 0.1 Hz. An amplitude of 20 mV was used based on the data of performed Kronig-Kramers analysis.

3. Results and discussion

3.1. Cathodic electrodeposition of MoS₂

To develop a necessary understanding of the chosen system, linear sweep voltammetry (LSV) measurements at increasing potential scan rates were performed. The cathodic deposition of MoS₂ occurs according to Eq. (2):



The open circuit potential was chosen as the starting point and the potential was scanned toward -1.2 V (Fig. 1). At a low scan rate (5 mV s^{-1}) no clear reduction peaks can be distinguished. MoS_{2-x} electrodeposition occurs alongside hydrogen evolution. When the potential scan rate is increased to 20 mV s^{-1} and more, a small peak in the reduction region (-1.0 V to -1.15 V) becomes apparent, after which further cathodic current increase results in hydrogen evolution. The peak shift towards more cathodic values with increased potential scan rate suggests slow reaction kinetics, as the current is slow to respond to the swift change in the potential. This may be attributed to a slow charge transfer step or diffusion, but the detailed kinetics of this reaction were not the objective of this study.

Hence, MoS_{2-x} films were deposited under a potentiostatic mode, in the range of -0.8 V to -1.2 V to observe film formation nearby the reduction peak. The surface morphology and chemical composition of as-deposited films depends on the potential applied (Fig. 2). Thin layers that replicate the surface morphology of the substrate are obtained at low cathodic potentials (Fig. 2a). At an intermediate deposition potential of -1.0 V a rough and nodular surface structure with some cracks is formed (Fig. 2b). At even higher potentials (-1.2 V) the deposited films were observed to peel off from the substrate when drying. As was expected from LSV, the increase of the cathodic deposition potential results in higher quantities (in at. %) of Mo and S in the electrodeposits at a constant deposition time (Fig. 2c). Larger quantities of Mo and S can be also obtained by increasing the deposition time (Fig. 2d). Thus, by increasing the deposition time it is possible to carry out electrodeposition at lower potentials, in order to avoid intense hydrogen evolution. As it was mentioned, the as-deposited films are thin, and therefore a strong signal of the Cu substrate is visible in the EDX

analysis. However, the atomic % of Cu decreases when a larger amount of Mo and S is deposited at higher potentials or deposition times (Fig. 2c and d). It should be noted, that a significant amount of oxygen is also present in the samples, and its relative amount increases with applied potential. This could be attributed to the following issues: a) some amount of unreacted molybdate from the solution can electrodeposit alongside MoS_{2-x}; b) due to the oxidation of MoS_{2-x} active centres in air.

3.2. Electrocatalytic activity for hydrogen evolution reaction

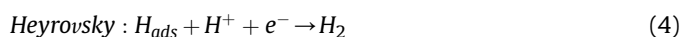
3.2.1. Influence of electrodeposition potential

The electrodeposited MoS_{2-x} films were all characterized in terms of their ability to catalyse the hydrogen evolution reaction in acidic media. All experiments were carried out with freshly-prepared MoS_{2-x}, as it was found that the electrocatalytic activity for HER severely decreases after the films had been dried and stored in air (likely due to surface active site oxidation). Thus, the as-deposited films were removed from the electrolyte, rinsed with distilled water and 2-propanol, and then immediately transferred into $0.5 \text{ M H}_2\text{SO}_4$. The solution was used for a comprehensive characterization of the obtained films (as described in the experimental section), consisting of EIS, HER voltammetric sweeps, and galvanostatic stability experiments (Fig. 3). Several tendencies were revealed from the analysis.

It is evident that even a thin coating of MoS_{2-x} (deposited at -0.8 V) already greatly increased HER activity compared to the bare substrate (Fig. 3a). An increase in the cathodic deposition potential resulted in better catalytic activity and lower onset overpotentials (measured at 1 mA cm^{-2}): 0.232 V and -0.122 V vs. RHE for MoS_{2-x} deposited at -0.8 V and -1.2 V respectively. The reason for this improvement is mostly linked to the increase in catalyst loading, i.e. a higher amount of electrodeposited MoS_{2-x}, or a lesser amount of Cu in EDX spectra. A more in-depth analysis of the catalytic activity follows in section 3.3.

The hydrogen evolution rate depends both on the chemical composition of a cathode and surface morphology. An exponential relation between MoS_{2-x} electrodeposition potential and HER exchange current density (j_0) was observed (Fig. 3b). Although the average thickness of the films deposited at -1.0 V to -1.2 V does not differ significantly from each other, the increase in j_0 is evident. Unfortunately, further increasing of the deposition potential did not obey this exponential relation, probably because of the unfavourable changes in the film's formation that occur due to severe hydrogen evolution.

Another result showing the impact of electrodeposition potential on the intrinsic activity of the film is the calculated HER Tafel slope (Fig. 3c). The mechanism of cathodic hydrogen evolution occurs through a few intermediate stages, and each of these can be rate limiting:



If the Volmer adsorption reaction is the rate limiting step, a Tafel slope of 120 mV dec^{-1} would be expected. If either the Heyrovsky or Tafel recombination steps are rate limiting, the Tafel slope would be 40 or 30 mV dec^{-1} . For the investigated samples, Tafel slopes generally fell within the 40 – 50 mV dec^{-1} range, showing mixed HER kinetics. One exception from the given trend was the MoS_{2-x} film, deposited at -1.2 V. The Tafel slope for this sample was markedly higher at 65.9 mV dec^{-1} (Fig. 3c). The increase in the Tafel

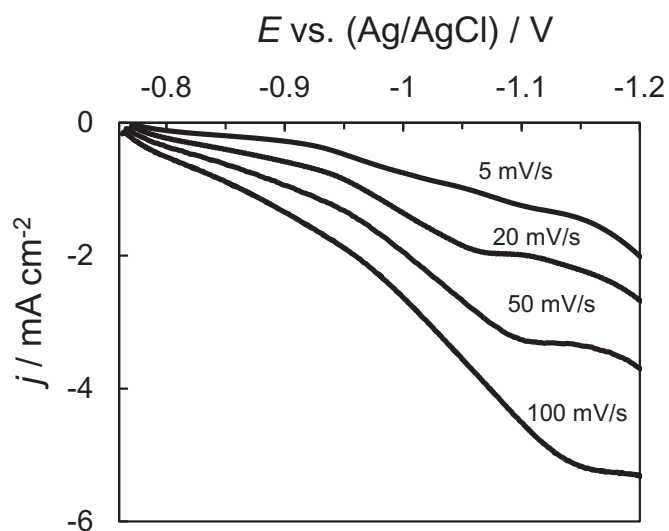


Fig. 1. LSV curves of MoS_{2-x} electrodeposition on a bare Cu wire substrate in 25 mM TTM + 10% 2-propanol.

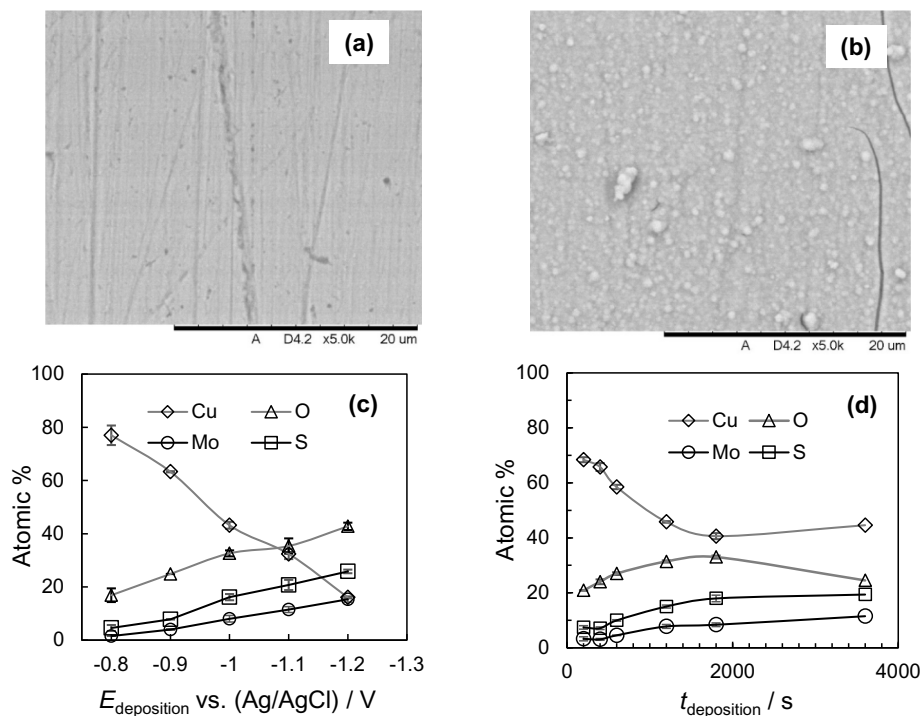


Fig. 2. SEM images of the surface morphology of MoS_{2-x} films, electrodeposited for 600 s at -0.8 V and -1.0 V respectively (a, b). Influence of applied potential at fixed deposition time of 600 s (c) and deposition time at fixed potential of -1.0 V (d) on composition of MoS_{2-x} films electrodeposited on copper.

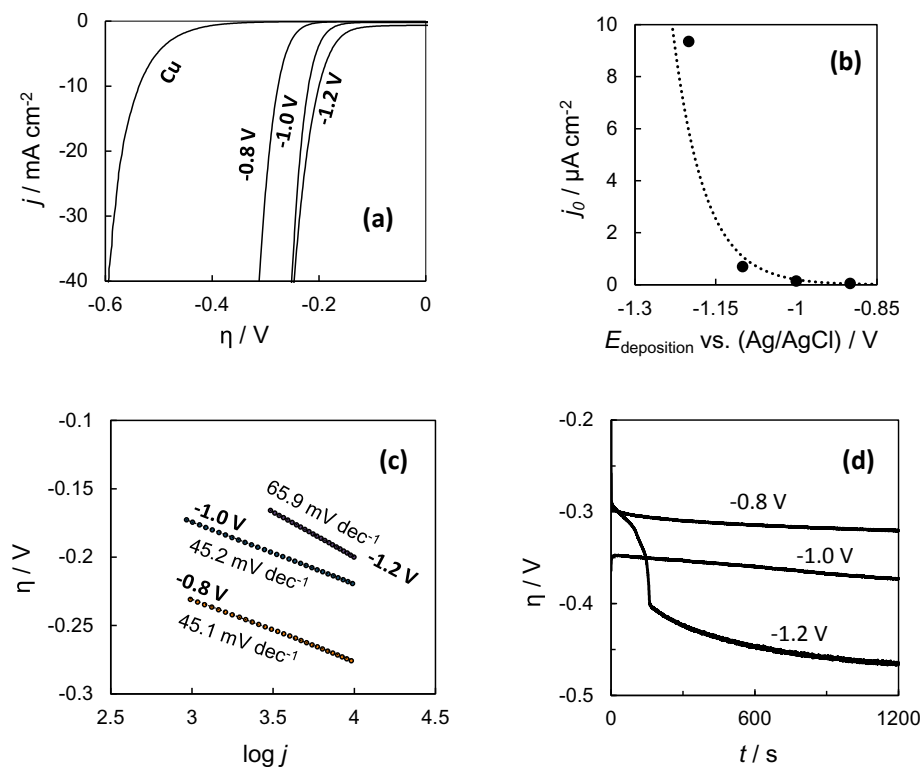


Fig. 3. Hydrogen evolution electrocatalysis data: 10th cycle of HER polarization curve of MoS_{2-x} films, electrodeposited at indicated potentials for 600s, scan rate 10 mV s⁻¹, 0.5 M H₂SO₄. Bare Cu substrate added for comparison (a); HER exchange current density as a function of MoS_{2-x} electrodeposition potential (b); Tafel slopes of the respective samples (c); Galvanostatic (-40 mA cm⁻²) stability experiments (d) – see details in the text.

slope shows an unfavourable deviation from the dominating Volmer-Heyrovsky or Volmer-Tafel HER mechanism. This may be related to the occurrence of side reactions during electrodeposition at this relatively high potential, and the changes in the deposited

MoS_{2-x} films. The Mo: S ratio of this film was also the lowest at 1:1.68.

Finally, the electrochemical stability of the MoS_{2-x} films was evaluated by chronopotentiometry at moderately harsh working

conditions of -40 mA cm^{-2} for 20 min (Fig. 3d). On average, the films lost around 5% activity over the measurement, but MoS_{2-x} film deposited at -1.2 V underwent complete destruction (peeling off from the substrate) within the first 200 s of the experiment. These experiments show that, although electrodeposition at higher potentials seems to yield films with better electrocatalytic activity, their stability is unacceptable.

3.2.2. Influence of deposition time

Deposition time also affects the elemental composition of the MoS_{2-x} layers (Fig. 2 b), and consequently can change their catalytic activity. Taking into account SEM/EDX analysis and stability of the films, deposition at a constant potential of -1.0 V but for different times (200 s–7200 s) was chosen for further investigation (Fig. 4). Indeed, a longer deposition time had a significant effect on the MoS_{2-x} films' electrocatalytic activity. The overpotential for HER (at 10 mA cm^{-2}) changed from -0.285 V to -0.180 V (vs. RHE) when the deposition time was increased from 200 s to 7200 s (Fig. 4a), which may be attributed to increasing catalyst loading. However, a diminishing gain in catalytic activity is observed when deposition times are increased from 1800 s to 7200 s. A limit is reached where the electrode's total catalytic activity no longer depends on catalyst loading.

The exchange current density increases linearly with deposition time in the entire investigated range up to 7200 s (Fig. 4b). This is a particularly promising result, as it implies a possibility to reach relatively high exchange current densities under mild electrodeposition conditions. The Tafel slopes of these samples also show an interesting behaviour (Fig. 4c). A minimum of 42.5 mV dec^{-1} is reached when the MoS_{2-x} film has been deposited for 1800 s. The reason for this outcome could be linked to the formation of

different active sites, or that an optimum catalyst loading is reached, where a further increase of deposition time begins to impede charge transfer in the semiconductor MoS_{2-x} material.

The electrochemical stability of these films does not necessarily correlate to their catalytic activity. Stability tests under the previously described conditions showed that thinner (short deposition time) and more compact films can lose less than 1% (in terms of overpotential) of their initial activity over the experiment. For the film deposited for 1800 s, a larger 2.9% decrease in catalytic activity was observed. Finally, the film with the longest deposition time in our experimental series (7200 s) only had a 1.3% loss from initial activity. These results show that the most electrochemically stable MoS_{2-x} films should have either a compact, or a well-evolved and rough surface morphology.

An electrodeposited MoS_{2-x} film with the highest electrocatalytic activity for HER was compared with that of other MoS_2 and WS_2 based materials, synthesized by various methods (Table 1). It should be pointed out, that due to difficulties in assessing the electrocatalytically active surface area most reported current densities are normalized to a geometric surface area. Usually bigger catalyst loading results in better catalytic activity. In addition, composites with high-surface-area substrates (e.g. carbon cloth, nanowires) have been reported to exhibit the best catalytic activity and stability.

3.3. Electrochemical impedance spectroscopy

3.3.1. Catalyst-solution interface evaluation

EIS has been shown to provide useful information on HER catalytic materials that is supplementary to more typical experiments like steady-state polarization, and can give insight into the

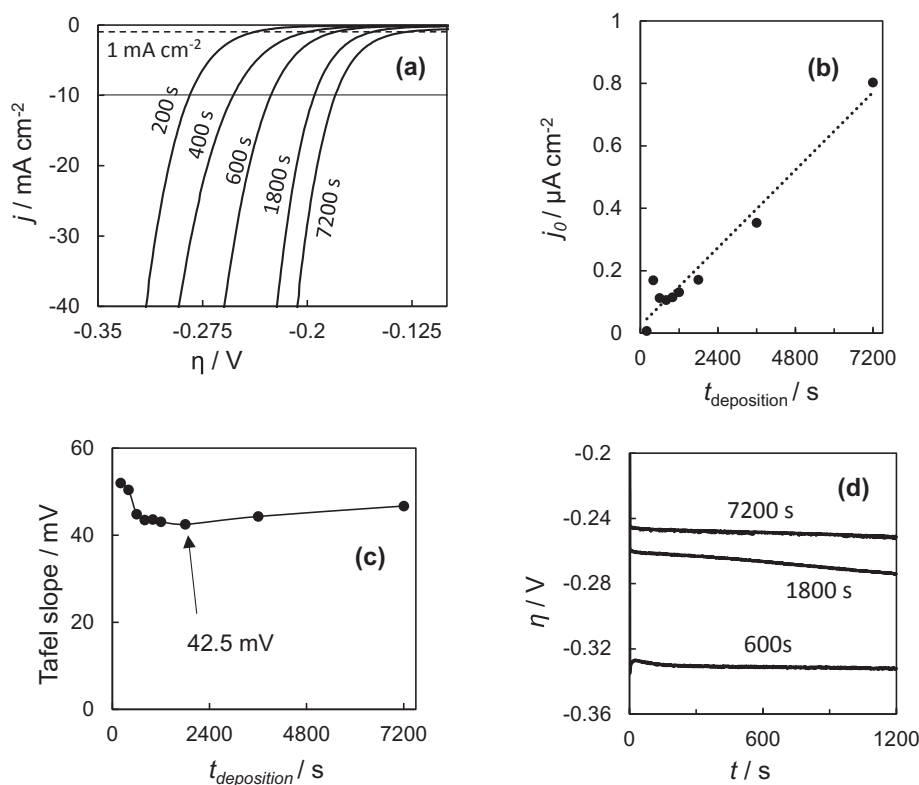


Fig. 4. iR-corrected 10th HER polarization curve of MoS_{2-x} films, electrodeposited at -1.0 V (vs. Ag/AgCl) for indicated deposition time (a), scan rate 10 mV s^{-1} , $0.5 \text{ M H}_2\text{SO}_4$; HER exchange current density as a function of deposition time (b); Relation between electrodeposition time and HER Tafel slope (c); galvanostatic stability measurement (at -40 mA cm^{-2}) curves (d).

Table 1
Comparison of key HER catalytic parameters for WS₂ and MoS₂ based catalysts.

Catalyst	j/mA cm ⁻²	-E _j /mV	Tafel slope/mV dec ⁻¹	Synthesis method	Reference
Ni–MoS ₂	10	310	47	Hydrothermal	[35]
GO/WS ₂		180	67	Electrodeposition	[36]
VG/CC/MoS ₂		78	53	Hydrothermal	[37]
CC/CoMoS _x		100	70	Electrodeposition	[38]
GC/MoS ₂ film		202	48	Electrodeposition	[39]
CC/MoS ₂	86	250	50	Solvothermal	[40]
Ti/MoS ₂	30	250	–	Hydrothermal	[41]
CC/WS ₂	42	300	68	Thermolysis	[42]
rGO/WS ₂	23	300	58	Hydrothermal	[43]
CC/Mo–W–S	10	198	54	Electrodeposition	[44]
MoO ₃ –MoS ₂		254	–	CVD/sulfidization	[45]
Amorph. MoS ₃		242	–	Electrodeposition	[25]
Exfol. MoS ₂		207	–	Liquid exfoliation	[46]
MoS _{2-x}		180	44	Electrodeposition	This work

mechanic or kinetic phenomena of the system under investigation [47]. In this study, the EIS spectra were obtained prior to the polarization measurements, in the same working electrolyte of 0.5 M H₂SO₄. A cathodic overpotential of –0.1V was chosen, as it represents a potential window where the Faradaic reaction (hydrogen evolution) occurs at a low rate, and a lower disturbance of the pre-electrode layer by hydrogen bubbles is expected.

Under these experimental conditions, the low-frequency current response to the potential perturbation should be caused mainly by the adsorption of H onto the active sites of the MoS_{2-x} film. Because the majority of active centres are S vacancies and Mo edges (with respective free hydrogen adsorption energies of $\Delta G^H_0 \approx -0.095$ eV, $\Delta G^H_0 \approx 0.115$ eV [12]), specific H⁺ adsorption had to assert during measurements by EIS and further characterization of the catalyst-solution interface. The characteristic impedance spectra are shown in Fig. 5. An identical high-frequency inductive response was observed for all samples. Although it did not seem to vary with electrodeposition time (and as such was likely not related to the occurring changes in the electrodeposited MoS_{2-x} films), it was also taken into account when fitting the data to equivalent electrochemical circuit models.

All of the impedance spectra have an almost entirely capacitive profile in the low-frequency range, but at higher frequencies (~1000 Hz–100 Hz) the beginning of a small semicircle can be distinguished (see Fig. 5a and insert). As is seen from Bode plots (Fig. 5b and c), a longer deposition time resulted in lower impedance magnitudes. When a thicker layer of a semiconductor is deposited, an opposite result would be expected – the impedance magnitude should increase. It confirms that the measured EIS spectra reflect the electrocatalytic activity of the MoS_{2-x} films. However, in order to model the spectra using discrete elements, both the double layer and adsorption capacitances should be taken into account. Therefore, the equivalent electric circuit (EEC) used for fitting has to involve elements attributed to the capacitance of the double electric layer (C_{dl}) and capacitance describing the specific adsorption of hydrogen onto the active sites of MoS_{2-x} film (C_a). Thus, the results were fitted to the EEC shown in Fig. 6.

This EEC has been often used to model reactions with a consecutive adsorption step. The inductance element has been added in order to fit the spectrum in the entire measured frequency range. The quality of the fit was evaluated by the chi-square and lowest sum of squares tests, by checking the randomness of the fit residuals, low relative standard deviations (normally less than 5%), and applying statistical F-test and t-test analysis. The model was found to fit the spectra well and conforms the requirements of performed statistical tests.

A constant phase element (CPE_a, Fig. 6) fits the experimental

data better than a simple capacitance element; the obtained values of T were recalculated into capacitance, C_a , using Brug et al.'s formula, Eq. (6) [48]:

$$C_a = T_a^{\frac{1}{n}} \left(\frac{1}{R_s + R_{ct}} + \frac{1}{R_a} \right)^{1-\frac{1}{n}} \quad (6)$$

where T_a is the parameter related to the electrode capacitance, n is the constant phase exponent; R_s , R_{ct} and R_a are uncompensated, charge transfer, and adsorption resistances, respectively.

This EEC describes an EIS spectrum that has two time constants. The process occurring at high frequencies is characterized by ($C_{dl}-R_{ct}$), and the corresponding time constant is τ_1 . Here C_{dl} is the double-layer capacitance, and R_{ct} is the charge transfer resistance of the Faradaic process. The (CPE_a-R_a) circuit represents the low frequency time constant τ_2 . Its presence is caused by the hydrogen adsorption reaction. Some variation becomes evident when the time constants are plotted against the electrodeposition time of the MoS_{2-x} films (Fig. 7). The high frequency time constant τ_1 approaches a maximum of 0.067 s, and the low frequency τ_2 reaches a minimum of 1.48 s for the film electrodeposited for 1000 s, and is lowest for films that have been deposited for 400–1200 s. This tendency broadly corresponds to the change in Tafel slope. As it is seen in Fig. 4d, although the total electrode activity increases with deposition time, part of that increase should be attributed to changes in the electrocatalytically active surface area rather than the intrinsic activity of the material.

The variations of the double layer capacitance C_{dl} , adsorption capacitance C_a , and adsorption resistance R_a are presented in Fig. 8. Both C_{dl} and C_a increase with deposition time, but the double layer capacitance at shorter deposition times remains larger than C_a . Such high values of C_{dl} are defined by a large real area of the obtained surface in comparison with the flat geometric surface area. Therefore, it is even higher than C_a , whose values are defined by both the roughness of the surface and electric current response to the reversible variations of surface coverage of adsorbate under the electrode potential perturbation during faradaic hydrogen evolution process.

However, when the films have been deposited for 1800 s and longer, the adsorption capacitance grows larger than C_{dl} . This is likely related to an increase in the number of active sites, and a consequent increase of coverage of the electrode surface by H_{ads}. The adsorption-related resistance R_a follows an exponential extinction curve, and almost plateaus at 226 Ω cm² for the longest deposition time film, which could be attributed to the appearance of charge transfer limitations in the growing MoS_{2-x} film.

This can be further related to the observed limit in HER

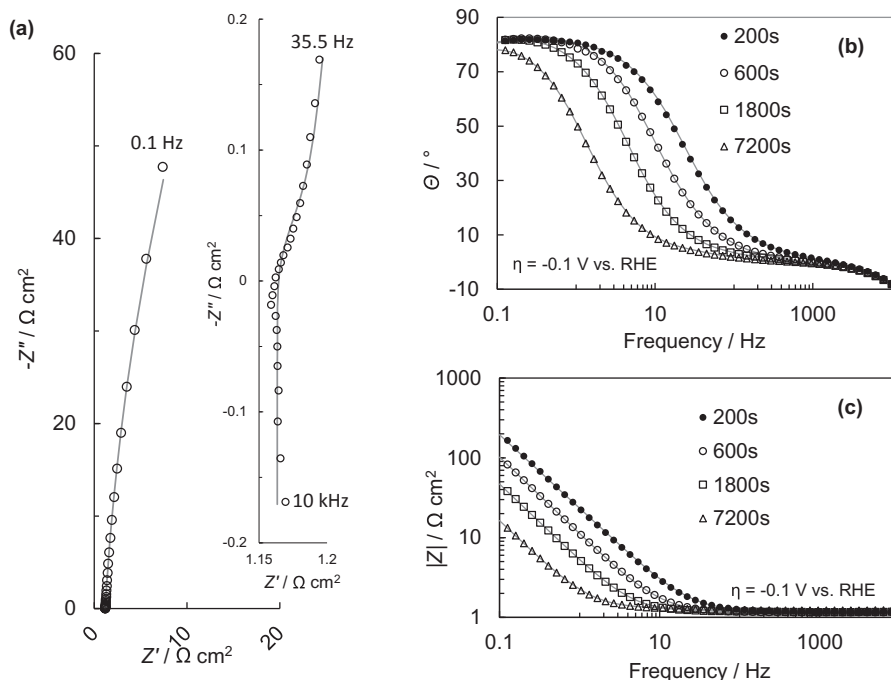


Fig. 5. EIS spectra obtained at overpotential -0.1 V of MoS_{2-x} films, electrodeposited for different deposition times: a representative complex-plane Nyquist spectrum of a MoS_{2-x} film electrodeposited for 1800 s (inset shows high frequency region) (a); the Bode impedance plots for respective films (b, c). Lines represent fitted data.

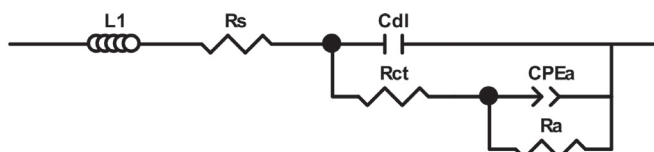


Fig. 6. Equivalent electric circuit used for EIS data fitting. L_1 – inductance element. R_s – electrolyte resistance; C_{dl} – element representing double layer capacitance; R_{ct} – Faradaic charge transfer resistance; CPE_a – constant phase element of the adsorption reaction; R_a – adsorption resistance.

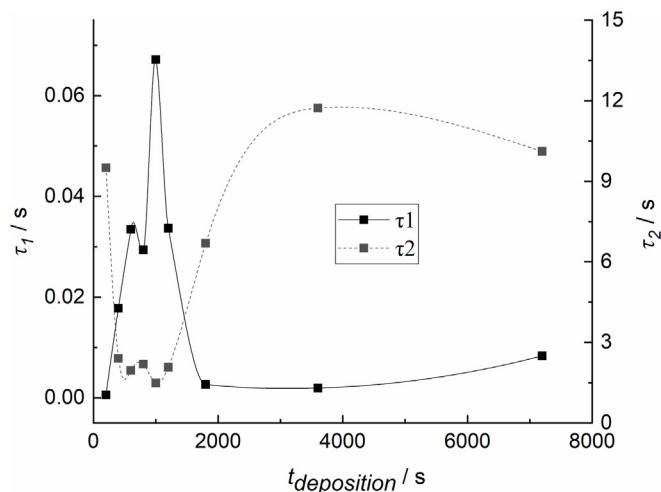


Fig. 7. The variation of time constants τ_1 (high frequency) and τ_2 (low frequency) with electrodeposition time.

electrocatalytic activity for the investigated films. With increasing film deposition time, the $\eta_{10\text{mA}}$ (overpotential at 10 mA cm^{-2} of HER current) and HER onset overpotential reach a plateau (Fig. 9). Thus, although further catalyst loading by electrodeposition is possible, the gain in electrocatalytic activity remains almost constant. In order to construct a more active electrode for HER electrocatalysis, it would be best to choose an optimal deposition time that results in better intrinsic activity, and increase the surface area of the substrate.

3.3.2. Electrochemical stability

The EIS methodology has also been applied to characterize the film and the catalyst-solution interface before and after stability tests (20 min under galvanostatic conditions at -40 mA cm^{-2}). A first EIS spectrum was generated prior to the test, and the second after, in the same electrolyte and applied conditions. The procedure allowed tracking any changes in the surface morphology, structure, or composition of the catalyst, by evaluating the differences in the impedance spectra. Indeed, a small but detectable signal was observed. Namely, the impedance magnitudes $|Z|$ and phase angles θ increased slightly after stability tests. The changes of the double layer and adsorption capacitances, as well as the charge transfer resistance, were estimated using the same EEC shown in Fig. 6. C_{dl} was found to decrease slightly after the stability test, which likely shows a decrease of the electrochemically active surface area. However, the R_a increased up to several hundred ohms for some samples. This correlates with the cathodic corrosion of amorphous MoS_{2-x} in the form of shortening $[\text{Mo}_3\text{S}_{13}]^{2-}$ polymer chains that has been hypothesized in Ref. [34]. A disrupted polymeric structure would indeed result in a hindered charge transfer step. These EIS results correspond well with the voltammetric stability curves (Fig. 4d). The capacitance of the specifically adsorbed species also changes after stability tests, and C_a was seen to increase slightly. The increase in adsorption capacitance is likely caused by another phenomenon related to the polymeric structure – the removal of terminal disulphide ligands, which results in the appearance of

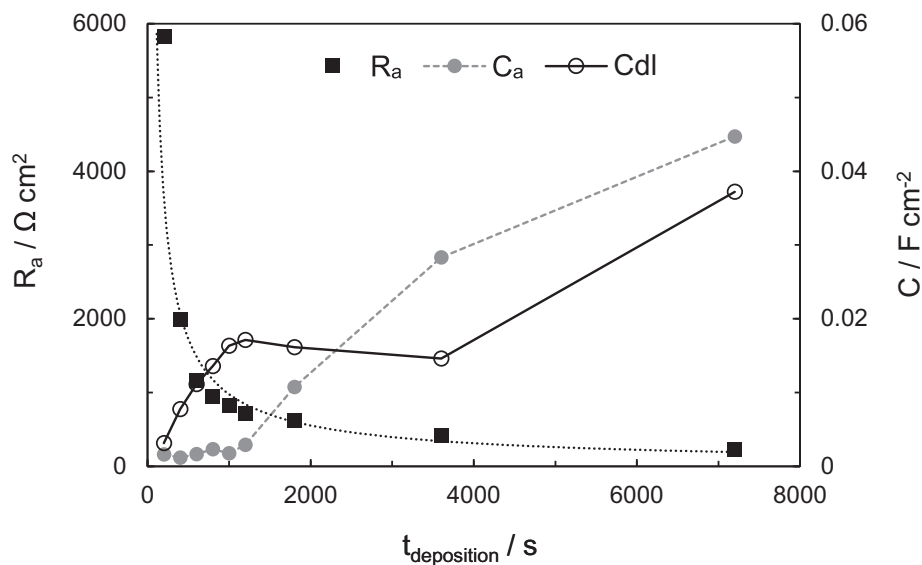


Fig. 8. EEC-calculated values of C_{dl} , C_a and R_a , and their dependence on the electrodeposition time of MoS_{2-x} films.

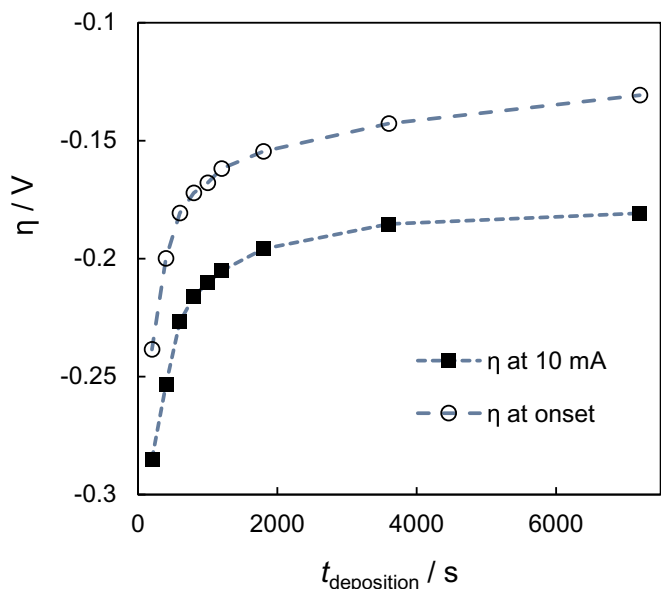


Fig. 9. HER onset overpotential (at -1 mA cm^{-2}) and overpotential, needed to reach 10 mA cm^{-2} of HER current, as a function of electrodeposition time.

new active sites (unsaturated Mo^{IV} sites). These experiments prove that, under vigorous hydrogen evolution conditions, the MoS_{2-x} films actually gain some active sites, but lose electrocatalytically active surface area and charge transfer conductivity, which limits the overall HER electrocatalytic activity of the material.

3.3.3. Estimation of electrocatalytically active sites

The electrocatalytically active surface area is not necessarily equal to the electrochemically active surface area, and attempts to normalize HER current density into electrochemically active surface area can skew the desired results. It should be noted, that there is no conventional method for active site calculation yet; research on MoS_2 -based HER catalysts usually faces difficulty in finding an appropriate way for number of active site estimation. However, researchers often report the number of active sites per cm^2 to compare their synthesized materials. Therefore, a following model to estimate the number of active sites attributed to the specific adsorption of H_{ads} by the application of EIS is discussed.

Firstly, to have a baseline for comparison, a calculation for a theoretical ideal catalytic film with 100% adsorbed hydrogen coverage is performed. From a geometrical point of view, an active site (sulphur vacancy) on the surface of a MoS_{2-x} lattice has a diameter of $\sim 0.5 \text{ nm}$ [12]. Therefore, a film of 1 cm^2 would then have $5.0 \cdot 10^{14}$ active sites. Assuming complete coverage with a monolayer of H_{ads} , the charge necessary to attain this monolayer would be $\sigma = 0.08 \text{ mC}$.

For the MoS_2 films, the charge necessary to attain a layer of adsorbed H was calculated from the EIS data, by taking into account only the adsorption capacitance. Values of C_a were recalculated into charge using following equation:

$$Q_a = C_a \eta \quad (7)$$

where Q_a is the charge used to obtain a layer of H_{ads} on the MoS_{2-x} film's surface; C_a is the adsorption capacitance; η is the overpotential applied for hydrogen evolution reaction, and at the same time for H_{ads} layer formation (-0.1 V).

It was assumed, that hydrogen adsorption is a one-electron process (Eq. (3)), and the one active site adsorbs a single H^+ . Thus, the maximum number of active sites can be calculated from Equation (8).

$$N_{\text{sites}} = \frac{Q_a \cdot N_A}{nF} \quad (8)$$

This yields values ranging from 10^{15} to 10^{16} sites cm^{-2} (see Table 2). Taking into account the difference between the real surface area and the geometric, these values are considered as being in good agreement with those obtained from geometric parameters as described above. In addition, the values estimated based on C_a data are close to those reported by other researchers working with different methods (e.g. roughness factor/capacitance calculations,

Table 2
Adsorption charge and active site calculation data.

$t_{\text{deposition}}/\text{s}$	$Q_a/\text{mC cm}^{-2}$	$N_{\text{active sites}} \cdot 10^{15}/\text{sites cm}^{-2}$
200	0.22	1.02
600	0.183	1.05
1200	0.317	1.81
3600	3.19	17.7
7200	5.05	27.9

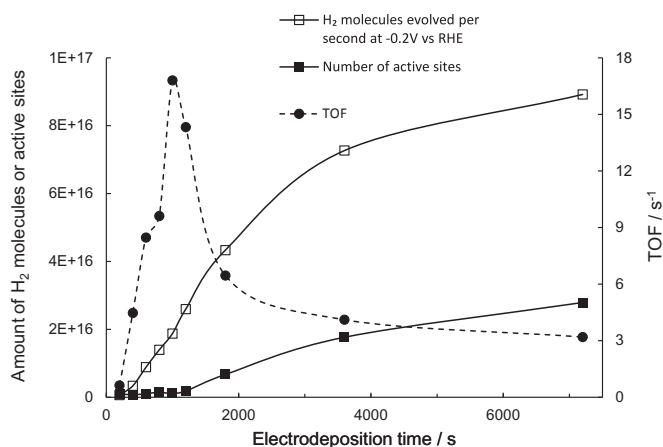


Fig. 10. Number of active sites and HER turnover frequencies at -0.2 V vs. RHE of MoS_{2-x} films, electrodeposited for different times (200 s–7200 s).

anodic oxidation, etc) to estimate active site densities for amorphous MoS_{2-x} [25,49].

The turnover frequencies (number of hydrogen molecules evolved per active site per second) for the films were compared at an overpotential of -0.2 V (Fig. 10). Active site number values per 1 cm^2 of the geometric area of the deposits were calculated from EIS data as described previously. The number of H_2 molecules evolved per second was calculated from respective current densities at overpotential -0.2 V , assuming that hydrogen evolution is a two-electron process. A maximum of turnover frequencies (TOF) of 15.3 s^{-1} was calculated for the MoS_{2-x} film, electrodeposited for 1000 s. Although the films, deposited for longer times (up to 7200 s) have better total activity, probably because of an optimum point in deposition time for per-site activity. These data also correspond well to the results presented in Fig. 4c, where the films deposited for 400 s–1800 s had the lowest Tafel slopes ranging from 42 to 44 mV dec^{-1} . A Tafel slope close to 40 mV dec^{-1} suggests that hydrogen evolution occurs through a Volmer-Heyrovsky mechanism, and that the electrochemical desorption (Heyrovsky) step is rate limiting [50,51]. The calculated turnover frequencies are in agreement with these data: the highest TOFs correspond to the lowest Tafel slopes. In addition, comparing the results with the time constants presented in Fig. 7, the same correlation is seen: the lowest adsorption time constants correspond to the highest turnover frequencies. The agreement between polarization and electrochemical impedance experiments again confirms the validity of using EIS to approximate the number of active sites on electrodeposited MoS_{2-x} .

Electrochemical impedance spectroscopy can be proposed as a simple way to determine various HER electrocatalyst properties: from activity and stability to the number of active sites and/or turnover frequency. Under carefully chosen electrochemical conditions, it is an entirely non-destructive method that can be seamlessly included in the experimental procedure and provide valuable data on the film/solution interface.

4. Conclusions

Nonstoichiometric MoS_{2-x} films were electrodeposited on copper substrates from a MoS_4^{2-} ion solution under potentiostatic conditions (-0.8 V to -1.2 V). It was found that electrodeposition at -1.0 V vs. Ag/AgCl provided more stable films, and this potential was taken as a reference to study the influence of the deposition time (200 s–7200 s) on the electrocatalytic activity of as-deposited

films. A MoS_{2-x} film, deposited for 7200 s, was comparable in terms of HER electrocatalytic activity to some of the best reported in the field so far (-0.18 V vs. RHE at 10 mA cm^{-2}). However, charge transfer limitations within the semiconductor lattice were found to limit catalytic activity. Under galvanostatic stability testing conditions (-40 mA cm^{-2}) the film lost $\sim 1.3\%$ of its initial activity over a period of 20 min. The loss in activity has been hypothesized to be caused by a shortening of polymeric $[\text{Mo}_2\text{S}_{13}]^{2-}$ chains. Electrochemical impedance spectroscopy measurements confirmed this, showing an increase in charge transfer resistance after the stability tests. EIS was also applied to estimate the active site density on the electrodeposited MoS_{2-x} . Values in the range of 10^{15} – 10^{16} active sites cm^{-2} were obtained. The number of active sites increased with deposition time, and followed the same trend as the exchange current density.

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